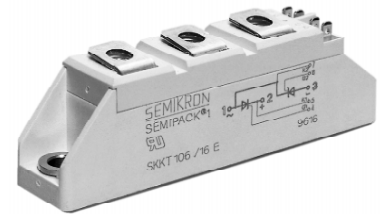


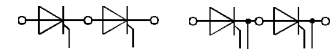
| | | | | | |
|-----------|-----------|----------------|--|---------------------|---------------------|
| V_{RSM} | V_{RRM} | $(dv/dt)_{cr}$ | I_{TRMS} (maximum value for continuous operation) | | |
| | V_{DRM} | | 40 A | | |
| V | V | V/ μ s | I_{TAV} (sin. 180; $T_{case} = 60\text{ }^{\circ}\text{C}$) | | |
| | | | 25 A | | |
| 700 | 600 | 500 | SKKT 19/06 D | SKKT 20/06 D | – |
| 900 | 800 | 500 | SKKT 19/08 D | SKKT 20/08 D | SKKT 20B08 D |
| 1300 | 1200 | 1000 | SKKT 19/12 E | SKKT 20/12 E | SKKT 20B12 E |
| 1500 | 1400 | 1000 | SKKT 19/14 E | SKKT 20/14 E | SKKT 20B14 E |
| 1700 | 1600 | 1000 | SKKT 19/16 E | SKKT 20/16 E | SKKT 20B16 E |

SEMIPACK® 1 Thyristor Modules

SKKT 19
SKKT 20
SKKT 20B



| Symbol | Conditions | SKKT 19 | SKKT 20 SKKT 20B | Units |
|---------------------|---|---|---------------------|-----------------------------|
| I_{TAV} | sin. 180; $T_{case} = 60\text{ }^{\circ}\text{C}$ $T_{case} = 85\text{ }^{\circ}\text{C}$ | 25 | 18 | A |
| I_D | B2/B6 $T_{amb} = 45\text{ }^{\circ}\text{C}$; P 3/180 $T_{amb} = 35\text{ }^{\circ}\text{C}$; P 3/180 F | 31 / 38 | 46 / 60 | A |
| I_{RMS} | W1/W3 $T_{amb} = 45\text{ }^{\circ}\text{C}$; P 3/180 | 42 / 3 x 30 | | A |
| I_{TSM} | $T_{vj} = 25\text{ }^{\circ}\text{C}$; 10 ms $T_{vj} = 125\text{ }^{\circ}\text{C}$; 10 ms | 320 | 280 | A |
| i^2t | $T_{vj} = 25\text{ }^{\circ}\text{C}$; 8,3 ... 10 ms $T_{vj} = 125\text{ }^{\circ}\text{C}$; 8,3 ... 10 ms | 510 | 390 | A ² s |
| t_{gd} | $T_{vj} = 25\text{ }^{\circ}\text{C}$; $I_G = 1\text{ A}$ $di_G/dt = 1\text{ A}/\mu\text{s}$ | 1 | | μs |
| t_{gr} | $V_D = 0,67 \cdot V_{DRM}$ | 1 | | μs |
| $(di/dt)_{cr}$ | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | 150 | | A/ μs |
| t_q | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | typ. 80 | | μs |
| I_H | $T_{vj} = 25\text{ }^{\circ}\text{C}$; typ./max. | 100 / 200 | | mA |
| I_L | $T_{vj} = 25\text{ }^{\circ}\text{C}$; $R_G = 33\ \Omega$; typ./max. | 250 / 400 | | mA |
| V_T | $T_{vj} = 25\text{ }^{\circ}\text{C}$; $I_T = 75\text{ A}$ | max. 2,3 | | V |
| $V_{T(TO)}$ | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | 1,0 | | V |
| r_T | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | 16 | | m Ω |
| I_{DD} ; I_{RD} | $T_{vj} = 125\text{ }^{\circ}\text{C}$; $V_{RD} = V_{RRM}$ $V_{DD} = V_{DRM}$ | max. 10 | | mA |
| V_{GT} | $T_{vj} = 25\text{ }^{\circ}\text{C}$; d.c. | 3 | | V |
| I_{GT} | $T_{vj} = 25\text{ }^{\circ}\text{C}$; d.c. | 150 | | mA |
| V_{GD} | $T_{vj} = 125\text{ }^{\circ}\text{C}$; d.c. | 0,25 | | V |
| I_{GD} | $T_{vj} = 125\text{ }^{\circ}\text{C}$; d.c. | 5 | | mA |
| R_{thjc} | cont. } per thyristor / sin. 180 } per module rec. 120 } | 1,2 / 0,6 1,3 / 0,65 1,35 / 0,68 | | $^{\circ}\text{C}/\text{W}$ |
| R_{thch} | | 0,2 / 0,1 | | $^{\circ}\text{C}/\text{W}$ |
| T_{vj} | | - 40 ... + 125 | | $^{\circ}\text{C}$ |
| T_{stg} | | - 40 ... + 125 | | $^{\circ}\text{C}$ |
| V_{isol} | a. c. 50 Hz; r.m.s.; 1 s/1 min | 3600 / 3000 | | V~ |
| M_1 | to heatsink } SI (US) units | 5 (44 lb. in.) $\pm 15\%$ ¹⁾ | | Nm |
| M_2 | to terminals } | 3 (26 lb. in.) $\pm 15\%$ | | Nm |
| a | | 5 · 9,81 | | m/s ² |
| w | approx. | 95 | | g |
| Case | → page B 1 – 95 | SKKT 19: A 5 SKKT 20: A 46 SKKT 20B: A 48 | | |



SKKT 19

SKKT 20
SKKT 20B

Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

Typical Applications

- DC motor control (e.g. for machine tools)
- AC motor soft starters
- Temperature control (e.g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

¹⁾ See the assembly instructions

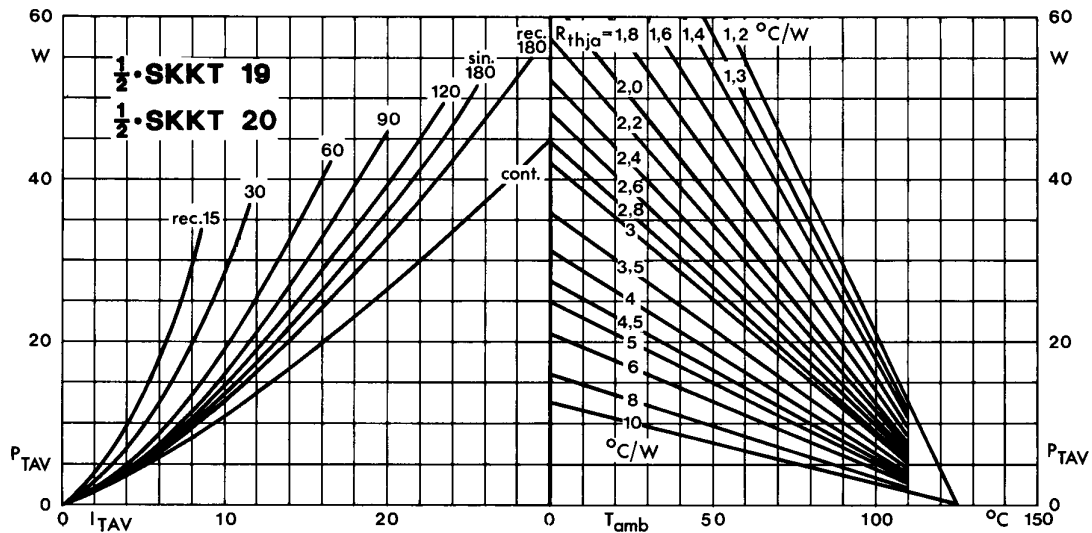


Fig. 1 Power dissipation per thyristor vs. on-state current and ambient temperature

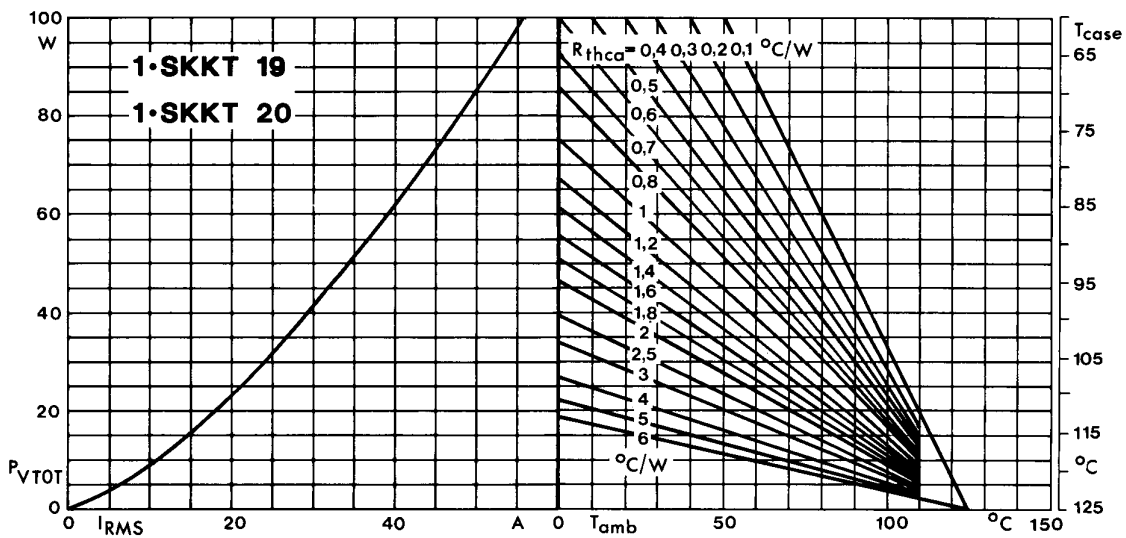


Fig. 2 Power dissipation per module vs. rms current and case temperature

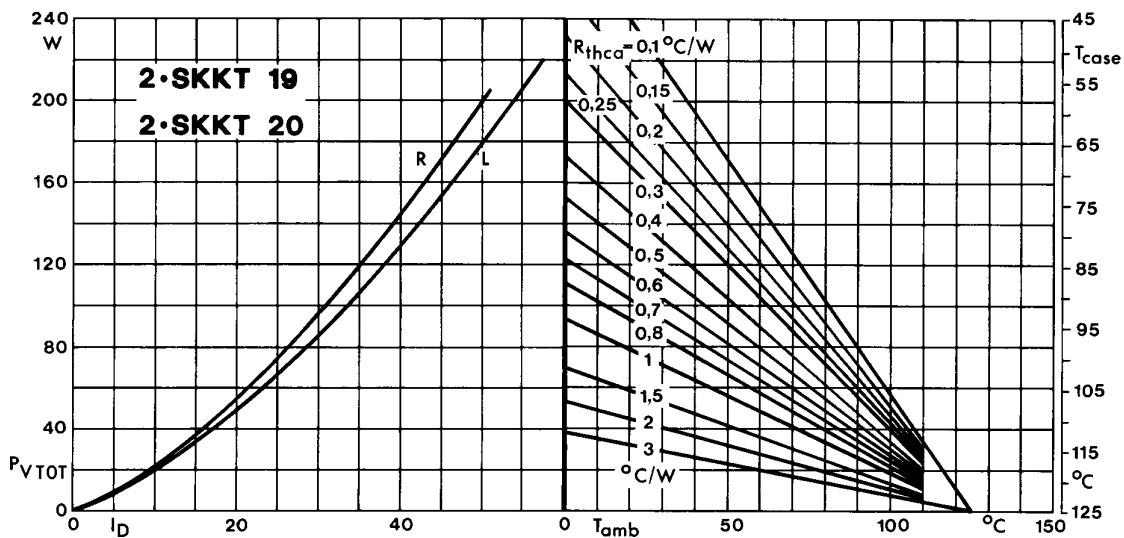


Fig. 3 Power dissipation of two modules vs. direct current and case temperature

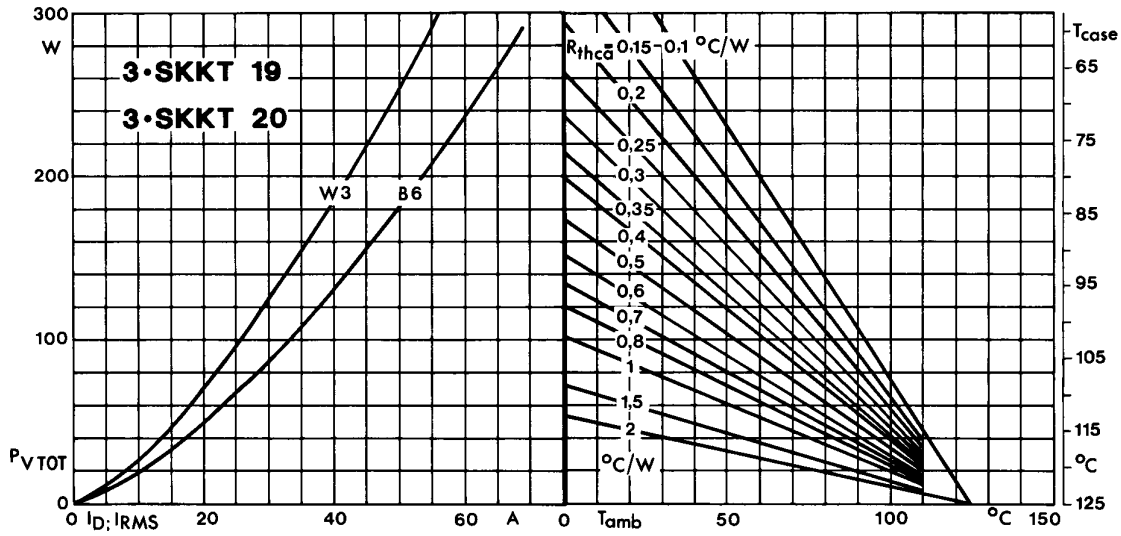


Fig. 4 Power dissipation of three modules vs. direct and rms current and case temperature

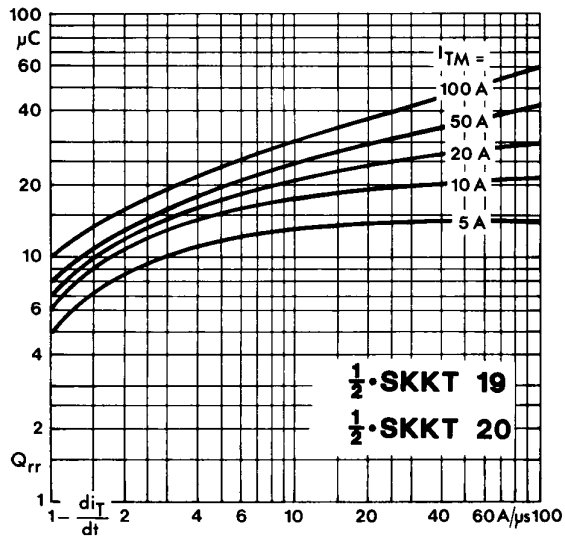


Fig. 5 Recovered charge vs. current decrease

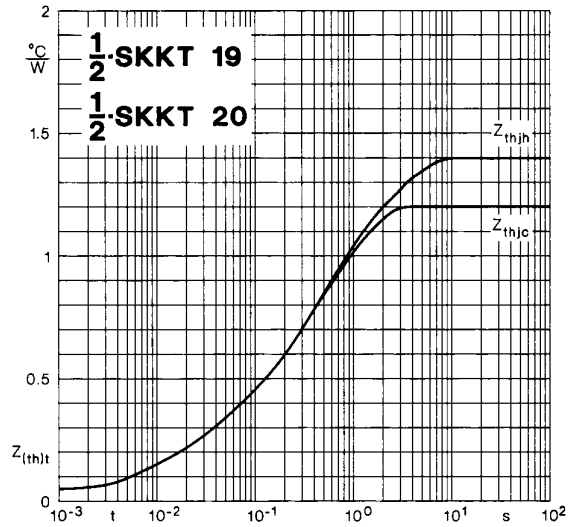


Fig. 6 Transient thermal impedance vs. time

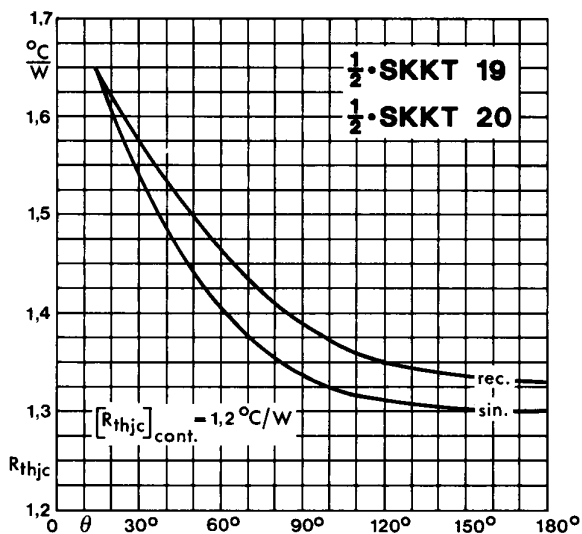


Fig. 7 Thermal resistance vs. conduction angle

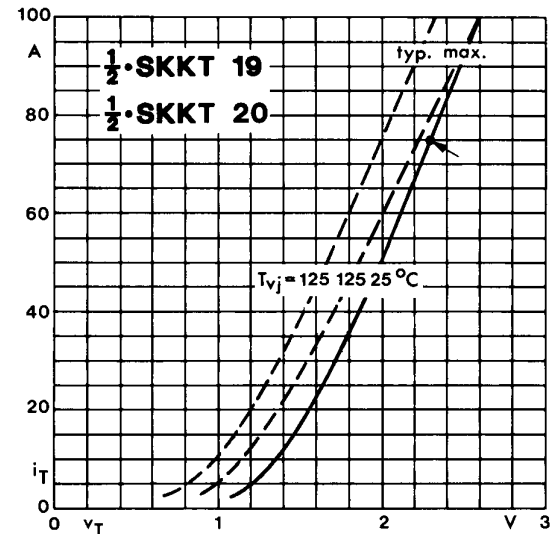


Fig. 8 On-state characteristics

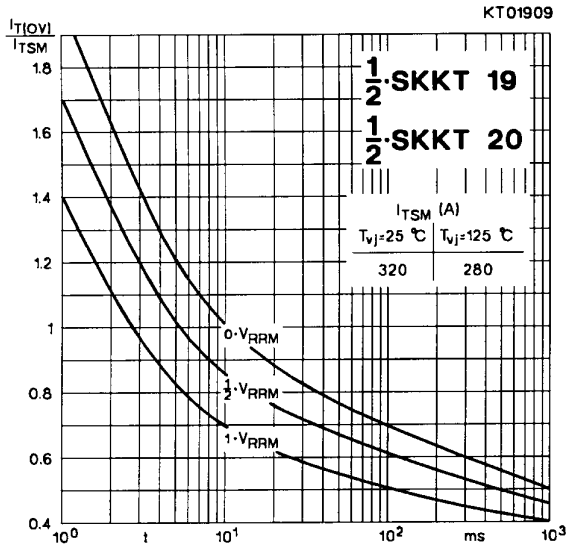


Fig. 9 Surge overload current vs. time

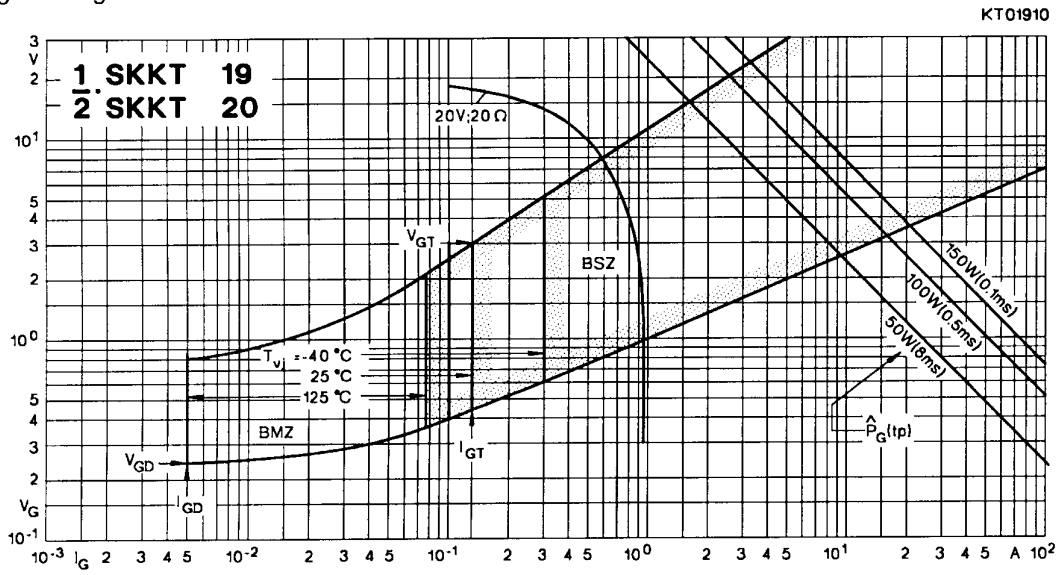


Fig. 10 Gate trigger characteristics

SKKT 19 ... 105

Case A 5

IEC 192-2: A 77 A

JEDEC: TO-240 AA

SEMIPACK® 1

UL recognized, file no. E 63 532



Dimensions in mm

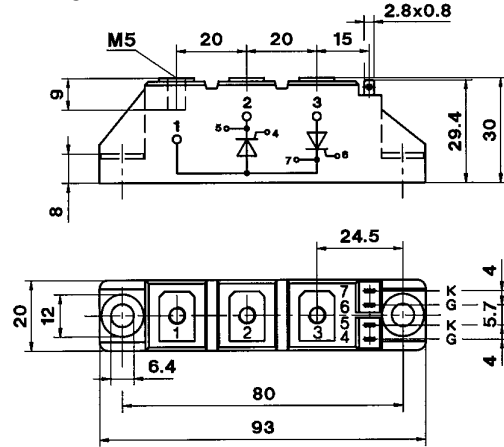
SKKT 20/ ... 106/

Case A 46

IEC 192-2: A 77 A

JEDEC: TO-240 AA

SEMIPACK® 1



Dimensions in mm

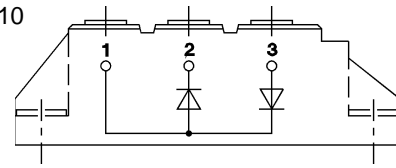
SKKH 26 ... 105

Case A 6



SKKD 26 ... 100

Case A 10



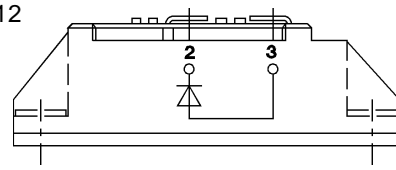
SKNH 56 ... 91

Case A 7



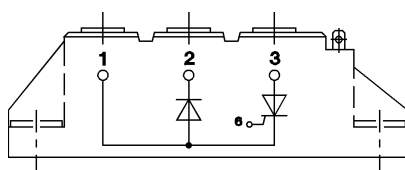
SKKE 81

Case A 12



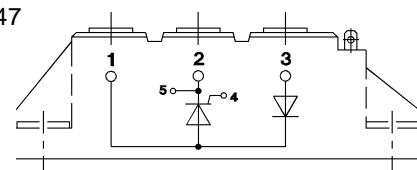
SKKL 56 ... 105

Case A 9



SKKH 27 ... 106

Case A 47



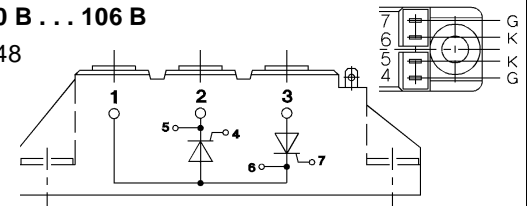
SKND 46 ... 81

Case A 19



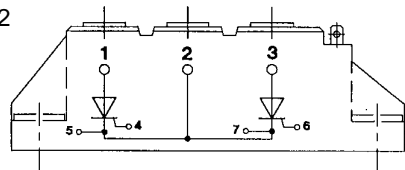
SKKT 20 B ... 106 B

Case A 48



SKMT 92

Case A 72



SKKL 42 ... 106

Case A 59

